2SD1423, 2SD1423A

Silicon NPN epitaxial planar type

For low-frequency amplification

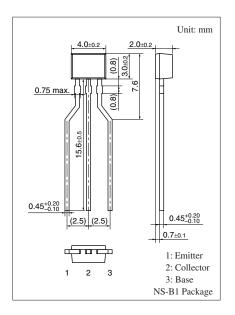
Complementary to 2SB1030 and 2SB1030A

■ Features

- Optimum for high-density mounting
- Allowing supply with the radial taping

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SD1423	V_{CBO}	30	V
(Emitter open)	2SD1423A		60	
Collector-emitter voltage	2SD1423	V _{CEO}	25	V
(Base open)	2SD1423A		50	
Emitter-base voltage (Coll	V _{EBO}	7	V	
Collector current	I_{C}	0.5	A	
Peak collector current	I_{CP}	1	A	
Collector power dissipation	P _C	300	mW	
Junction temperature	T_{j}	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	



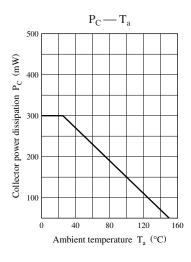
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

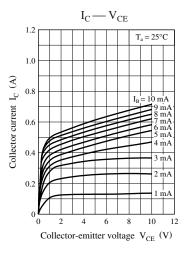
Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage	2SD1423	V_{CBO}	$I_C = 10 \mu\text{A}, I_E = 0$	30			V
(Emitter open)	2SD1423A			60			
Collector-emitter voltage	2SD1423	V _{CEO}	$I_C = 2 \text{ mA}, I_B = 0$	25			V
(Base open)	2SD1423A			50			
Emitter-base voltage (Collector open)		V_{EBO}	$I_E = 10 \ \mu A, I_C = 0$	7			V
Collector-base cutoff current (Emitter open)		I_{CBO}	$V_{CB} = 20 \text{ V}, I_E = 0$			0.1	μΑ
Collector-emitter cutoff current (Base open)		I_{CEO}	$V_{CE} = 20 \text{ V}, I_{B} = 0$			1	μΑ
Forward current transfer ratio		h _{FE1} *	$V_{CE} = 10 \text{ V}, I_{C} = 150 \text{ mA}$	85		340	_
		h _{FE2}	$V_{CE} = 10 \text{ V}, I_{C} = 500 \text{ mA}$	40			
Collector-emitter saturation voltage		V _{CE(sat)}	$I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$			0.6	V
Transition frequency		f_T	$V_{CB} = 10 \text{ V}, I_{E} = -50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance		C _{ob}	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		6	15	pF
(Common base, input open circuited)							

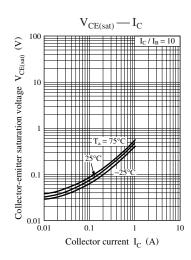
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

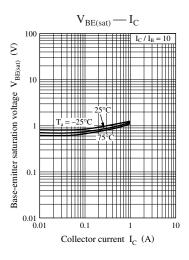
2. *: Rank classification

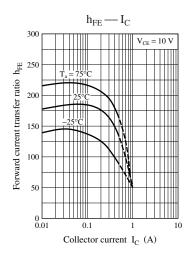
Rank	Q	R	S	
h _{FE1}	85 to 170	120 to 240	170 to 340	

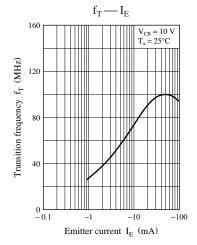


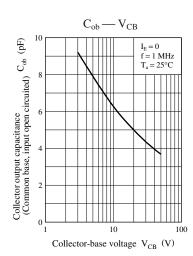












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